

KSD73

Low Frequency High Power Amplifier

- Collector-Base Voltage : V_{CBO} = 100V
- Collector Current : I_C = 5A
- Collector Dissipation : P_C = 30W (T_C=25°C)



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	5	Α
P _C	Collector Dissipation (T _C =25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = 1 \text{mA}, I_{E} = 0$	100			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 20 \text{mA}, I_B = 0$	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 1 \text{mA}, I_{C} = 0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 100 V, I_{E} = 0$			5	mA
h _{FE}	DC Current Gain	$V_{CE} = 10V, I_{C} = 1.0A$	70		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 5A, I_B = 0.5A$			2.0	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 5A, I_B = 0.5A$			1.5	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.3A$		20		MHz
V _{BE} (on)	Base-Emitter ON Voltage	$V_{CE} = 10V, I_{E} = 1.0A$		0.75		V

h_{FE} Classification

Classification	0	Y	
h _{FE}	70 ~ 140	120 ~ 240	

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Typical Characteristics

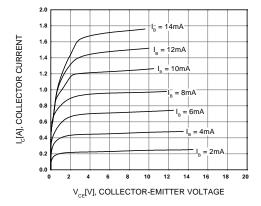


Figure 1. Static Characteristic

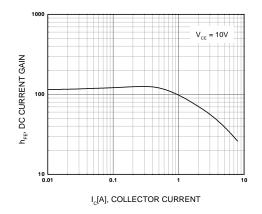


Figure 2. DC current Gain

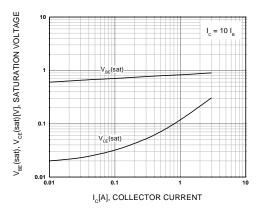


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

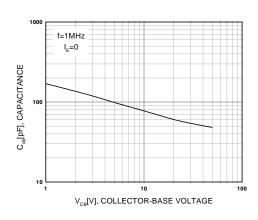


Figure 4. Collector Output Capacitance

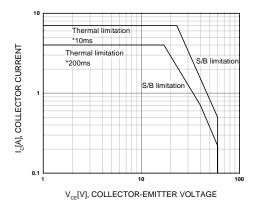


Figure 5. Safe Operating Area

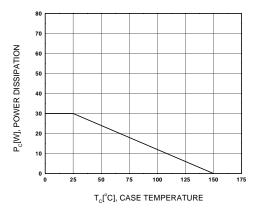
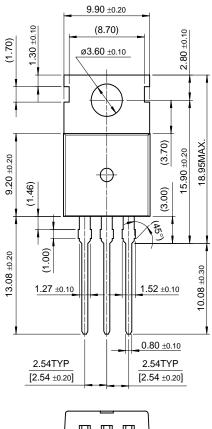


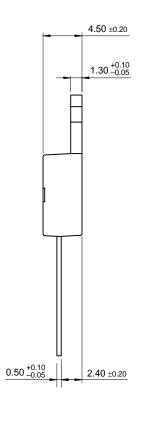
Figure 6. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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